HSMP-3812

Low distortion PIN attenuator diode

Description



Lifecycle status: Active



Features

The HSMP-381x family of PIN diodes are the ideal solution for low distortion attenuators. Ct=0.35pF, Rs@100mA=2.50hms, Tau=1800nSec, Fc=88kHz

HSMP-381x, 481x

Surface Mount RF PIN Low Distortion Attenuator Diodes



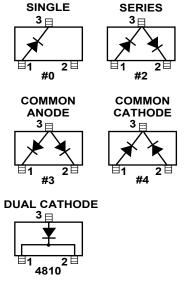
Data Sheet

Description/Applications

The HSMP-381x series is specifically designed for low distortion attenuator applications. The HSMP-481x products feature ultra low parasitic inductance in the SOT-23 and SOT-323 packages. They are specifically designed for use at frequencies which are much higher than the upper limit for conventional diodes.

A SPICE model is not available for PIN diodes as SPICE does not provide for a key PIN diode characteristic, carrier lifetime.

Package Lead Code Identification, SOT-23 (Top View)



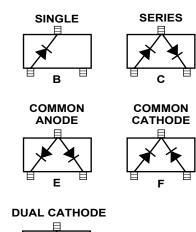
Features

- Diodes Optimized for:
 - Low Distortion Attenuating
 - Microwave Frequency Operation
- Surface Mount Packages
 - Single and Dual Versions
 - Tape and Reel Options Available
- Low Failure in Time (FIT) Rate[1]

Note:

 For more information see the Surface Mount PIN Reliability Data Sheet

Package Lead Code Identification, SOT-323 (Top View)





Absolute Maximum Ratings^[1] $T_c = +25^{\circ}C$

Symbol	Parameter	Unit	SOT-23	S0T-323
I _f	Forward Current (1 µs Pulse)	Amp	1	1
P _{IV}	Peak Inverse Voltage	٧	Same as V _{BR}	Same as V _{BR}
T,	Junction Temperature	°C	150	150
T	Storage Temperature	°C	-65 to 150	-65 to 150
θ_{ic}	Thermal Resistance [2]	°C/W	500	150

Notes:

- Operation in excess of any one of these conditions may result in permanent damage to the device.
 T_C = +25°C, where T_C is defined to be the temperature at the package pins where contact is made to the circuit board.

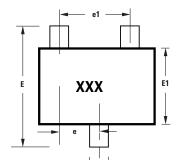
Electrical Specifications $T_c = +25^{\circ}C$ (Each Diode) Conventional Diodes

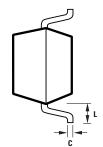
Part Number HSMP-	Package Marking Code	Lead Code	Configuration	Minimum Breakdown Voltage V _{BR} (V)	Maximum Total Capacitance C _T (pF)	Minimum Resistance at $I_{_{\rm F}}=0.01 {\rm mA}, \\ {\rm RH}\left(\Omega\right)$	Maximum Resistance at $I_F = 20 \text{mA},$ $R_L(\Omega)$	Maximum Resistance at $I_F = 100 \text{mA},$ RT (Ω)	Resistance at $I_F = 1 \text{ mA}$, $R_M (\Omega)$				
3810	E0	0	Single										
3812	E2	2	Series										
3813	E3	3	Common Anode										
3814	E4	4	Common Cathode	100	0.25	1500	10	2.0	40 to 70				
381B	E0	В	Single	100	100	100	100		0.35	1500	10	3.0	48 to 70
381C	E2	C	Series										
381E	E3	Е	Common Anode										
381F	E4	F	Common Cathode										
Test Conditi	ons			$V_R = V_{BR}$ Measure $I_R \le 10$ uA	$V_R = 50V$ f = 1MHz	$I_F = 0.01 \text{mA}$ f = 100 MHz	$I_r = 20 \text{mA}$ f = 100 MHz	$I_{F} = 100 \text{mA}$ $f = 100 \text{MHz}$	$I_F = 1 \text{mA}$ f = 100 MHz				

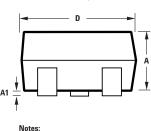
High Frequency (Low Inductance, 500 MHz – 3 GHz) PIN Diodes

Part Number HSMP-	Package Marking Code	Lead Code	Configuration	Minimum Breakdown Voltage V _{BR} (V)	Maximum Series Resistance $R_s(\Omega)$	Series Resistance $I_F = 1 mA,$ $R_M (\Omega)$	Typical Total Capacitance C _T (pF)	Maximum Total Capacitance C _T (pF)	Typical Total Inductance L _T (nH)	
4810	EB	В	Dual Cathode	100	2	40 70	0.25	0.4	1	
481B	EB	В	Dual Cathode	– 100	100 3	3	48 - 70	0.35	0.4	I
Test Conditi	ons			$V_{R} = V_{BR}$ Measure $I_{R} \le 10 \mu A$	$I_F = 100 \text{mA}$ $f = 100 \text{MHz}$	$I_F = 1 \text{mA}$ f = 100 MHz	$V_R = 50V$ f = 1MHz	$V_R = 50V$ f = 1MHz	f = 500MHz - 3GHz	

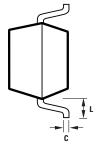
Package Dimensions Outline SOT-323 (SC-70)





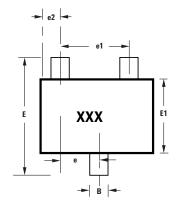


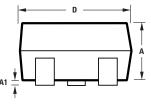
Notes:	
XXX-package marking	
Drawings are not to scale	



	DIMENSIONS (mm)		
SYMBOL	MIN.	MAX.	
Α	0.80	1.00	
A1	0.00	0.10	
В	0.15	0.40	
C	0.10	0.20	
D	1.80	2.25	
E1	1.10	1.40	
е	0.65 typical		
e1	1.30 typical		
E	1.80	2.40	
1	0 425 typical		

Outline 23 (SOT-23)





Notes:
XXX-package marking
Drawings are not to scale

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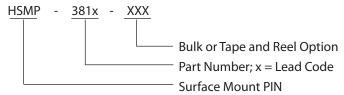
	DIMENSIONS (mm)		
SYMBOL	MIN.	MAX.	
Α	0.79	1.20	
A1	0.000	0.100	
В	0.37	0.54	
С	0.086	0.152	
D	2.73	3.13	
E1	1.15	1.50	
е	0.89	1.02	
e1	1.78	2.04	
e2	0.45	0.60	
E	2.10	2.70	
L	0.45	0.69	

Package Characteristics

Lead Material	Copper (SOT-323); Alloy 42 (SOT-23)
Lead Finish	Tin 100% (Lead-free option)
Maximum Soldering Temperature	260°C for 5 seconds
Minimum Lead Strength	2 pounds pull
Typical Package Inductance	2 nH
	0.08 pF (opposite leads)

Ordering Information

Specify part number followed by option. For example:



Option Descriptions

- -BLKG = Bulk, 100 pcs. per antistatic bag
- -TR1G = Tape and Reel, 3000 devices per 7" reel
- -TR2G = Tape and Reel, 10,000 devices per 13" reel

Tape and Reeling conforms to Electronic Industries RS-481, "Taping of Surface Mounted Components for Automated Placement."